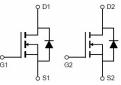


#### Feature

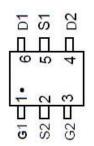
- 40V,5A
  R<sub>DS</sub> (ON) <36m Ω @V<sub>GS</sub>=4.5V TYP:30 m Ω
  R<sub>DS</sub> (ON) <45m Ω @V<sub>GS</sub>=2.5V TYP:35 m Ω
- Advanced Trench Technology
- Lead free product is acquired

## Application

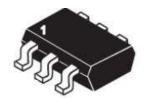
- Interfacing Switching
- Load Switching
- Power management



Schematic diagram



Marking and pin Assignment



SOT23-6 top view

#### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity (PCS)
AXXX	AP6900	Sot-23-6	7 inch	-	3000

## ABSOLUTE MAXIMUM RATINGS (T<sub>J</sub>=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	40	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Continuous Drain Current (Ta =25℃)	lo	5	A
Continuous Drain Current (Ta =70℃)	lo	3	А
Pulsed Drain Current	IDM	20	A
Power Dissipation	PD	1.6	W
Thermal Resistance from Junction to Ambient <sup>(4)</sup>	Reja	`78	°C/W
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>STG</sub>	-55~ +150	°C



## MOSFET ELECTRICAL CHARACTERISTICS(T<sub>J</sub>=25℃ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Туре	Max	Unit	
Static Characteristics			•				
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> =250µA	40	-	-	V	
Zero gate voltage drain current	Dss	V <sub>DS</sub> =40V, V <sub>GS</sub> = 0V	-	-	1	μA	
Gate-body leakage current	GSS	V <sub>GS</sub> =±20V,V <sub>DS</sub> = 0V	-	-	±100	nA	
Gate threshold voltage <sup>(3)</sup>	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250µA	1.0	1.4	2.5	V	
Drain-source on-resistance <sup>(3)</sup>	Р	V <sub>GS</sub> =10V, I <sub>D</sub> =4A	-	30	36	mΩ	
	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =3A	-	35	45		
Dynamic characteristics							
Input Capacitance	Ciss		-	435	-	pF	
Output Capacitance	Coss	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V, f =1MHz	-	58	-		
Reverse Transfer Capacitance	Crss		-	35	-		
Switching characteristics							
Turn-on delay time	t <sub>d(on)</sub>		-	10	-	ns	
Turn-on rise time	tr	V <sub>DD</sub> =20V, I <sub>D</sub> =4A,	-	8	-		
Turn-off delay time	t <sub>d(off)</sub>	V <sub>GS</sub> =10V, R <sub>G</sub> =3Ω	-	29	-		
Turn-off fall time	tr	-	-	12	-		
Total Gate Charge	Qg		-	11	-		
Gate-Source Charge	Qgs	VDS=20V, ID=3A,	-	2	-	nC	
Gate-Drain Charge	Qgd	- VGS=10V	-	2.5	-		
Source-Drain Diode characteristics		·			·	-	
Diode Forward voltage <sup>(3)</sup>	VDS	V <sub>GS</sub> =0V, I <sub>S</sub> =4A	-	-	1.2	V	
Diode Forward current <sup>(4)</sup>	ls		-	-	5.0	А	

#### Notes:

1. Repetitive Rating: pulse width limited by maximum junction temperature

2. Pulse Test: pulse width≤300µs, duty cycle≤2%

3. Surface Mounted on FR4 Board,t≤10 sec

#### **Test Circuit**

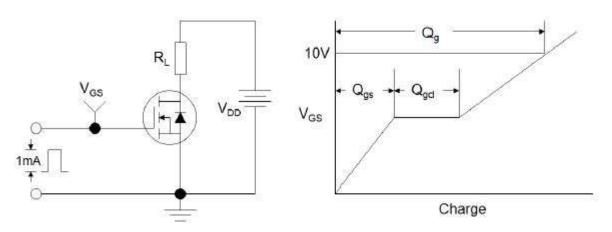


Figure1:Gate Charge Test Circuit & Waveform

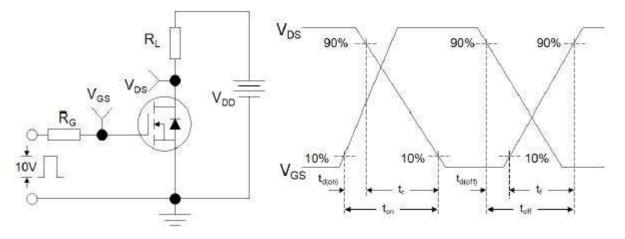


Figure 2: Resistive Switching Test Circuit & Waveforms

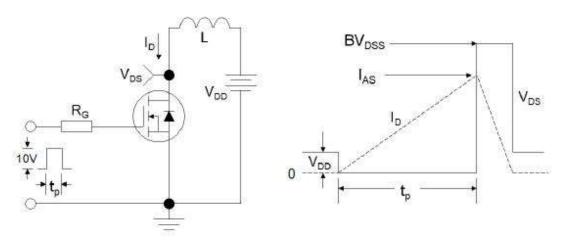
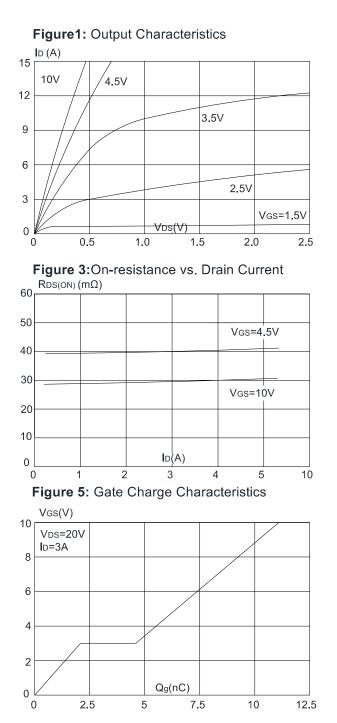
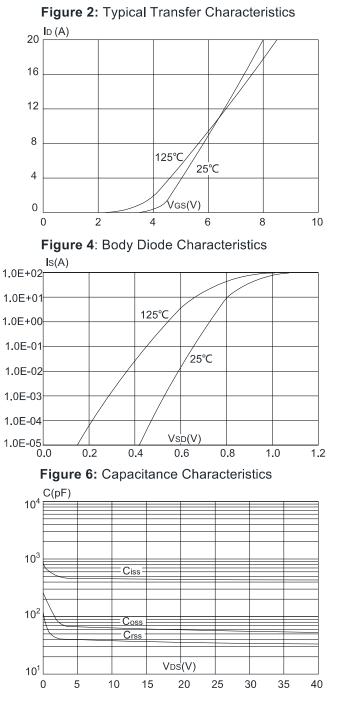


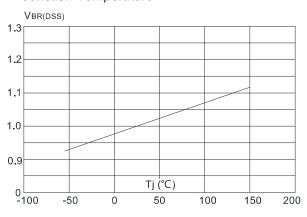
Figure 3:Unclamped Inductive Switching Test Circuit & Waveforms

## **Typical Performance Characteristics**

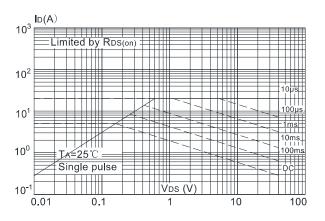




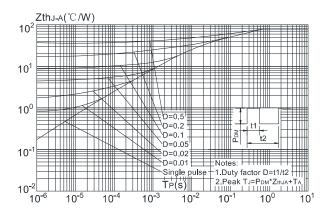
**Figure 7:** Normalized Breakdown Voltage vs. Junction Temperature







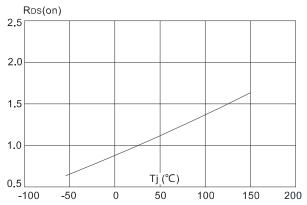




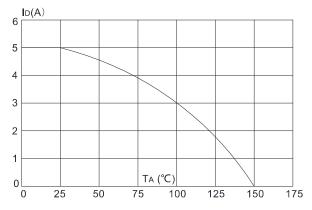
**Figure 8:** Normalized on Resistance vs. Junction Temperature

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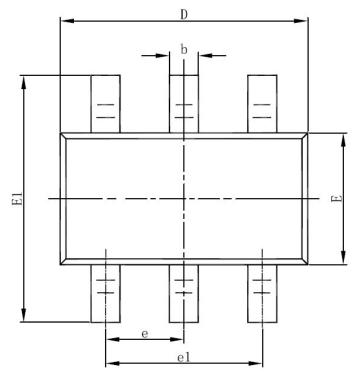
DATA SHEET

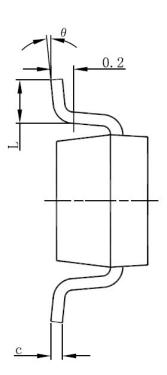


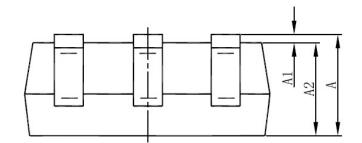
**Figure 10:** Maximum Continuous Drain Current vs. Ambient Temperature



#### SOT23-6 Package Information







Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
е	0.950(BSC)		0.037(BSC)		
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	



# **Revision History**

Revision	Release	Remark
V1.1	2022/02/10	Initial Release
V1.2	2024/04/24	Correction Mraking

## Disclaimer

The information given in this document describes the independent performance of the product,but similar performance is not guaranteed under other working conditions,and cannot be guaranteed when installed with other products or equipment. To achieve the required performance of the product in actual scenarios, the customer should conduct a complete application test to assess the functionality of the product.

Allpower assumes no responsibility for equipment failures result from using products at values that exceed the ratings, operating conditions, or other parameters listed in the product specifications.

The product described in this specification is not applicable for aerospace or other applications which

requires high reliability.Customers using or selling these products for use in medical,life-saving,or lifesustaining applications do so at their own risk and agree to fully indemnify.

Due to product or technical improvements, the information described or contained herein may be changed without prior notice.